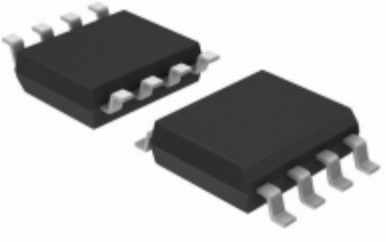





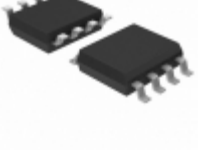
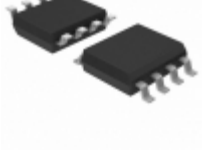



	<h2 style="color: red;">SI4214DDY-T1-E3</h2>	
	Hersteller-Teilenummer:	SI4214DDY-T1-E3
	Hersteller / Marke:	Vishay / Siliconix
	Teil der Beschreibung:	MOSFET 2N-CH 30V 8.5A 8SO
Datenblätter:	 SI4214DDY-T1-E3.pdf	
RoHs Status:	Bleifrei / RoHS-konform	
Lagerzustand:	New original, 43198 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	SI4214DDY-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET 2N-CH 30V 8.5A 8SO
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	43198 pcs Stock
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	3.1W
Verpackung / Gehäuse	8-SOIC (0.154", 3.90mm Width)
Supplier Device-Gehäuse	8-SO
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	8.5A
Rds On (Max) @ Id, Vgs	19.5 mOhm @ 8A, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	22nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	660pF @ 15V
Verpackung	Tape & Reel (TR)

SI4214DDY-T1-E3 ist neu im Original. Suche SI4214DDY-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI4214DDY-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI4214DDY-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI4212-RRDA-EVB Energy Micro (Silicon Labs) BOARD EVALUATION FOR SI4212</p>	 <p>SI4212-TRDX-EVB Energy Micro (Silicon Labs) KIT EVAL DAUGHT CARD FOR SI4212</p>	 <p>SI4214DDY-T1-GE3 Vishay / Siliconix MOSFET 2N-CH 30V 8.5A 8-SOIC</p>	 <p>SI4214DDY-T1-GE3 Electro-Films (EF1) / Vishay MOSFET 2N-CH 30V 8.5A 8-SOIC</p>
 <p>SI4214DDY-T1 VISHAY VISHAY SO-8</p>	 <p>SI4214DY SI SI4214DY SI</p>	 <p>SI4214DDY-T1 VISHAY SI4214DDY-T1 VISHAY</p>	 <p>SI4214DDY VISHAY SI4214DDY VISHAY</p>

heiße Teile

Mehr

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|--------------------|--------------------|-------------------|-------------------|-------------------|
| ⊛ SI4200-BMR | ↔ SI4200-GM | ↔ SI4200-GMR | D SI4200BM | ↔ SI4200DB-BMR |
| ⊣ SI4200DY-T1-E3 | ⊛ SI4201-BMR | D SI4201-GMR | ↔ SI4202DY | ↔ SI4205-BM |
| ⊛ SI4205-BMR | ⊣ SI4206-BM | ⊛ SI4206-BMR | ↔ SI4208-A-GMR | ↔ SI4208GM |
| D SI4209-A-GMR | ⊛ SI4210-C-GMR | ⊣ SI4210-D-GMR | ⊛ SI4210-GM | ↔ SI4210DY-T1-E3 |
| ↔ SI4210DY-T1-GE3 | ↔ SI4210DY-T1-GE3 | ⊛ SI4210GM | ⊣ SI4214DDY | ↔ SI4214DDY-T1-E3 |
| ↔ SI4214DDY-T1-GE3 | ↔ SI4214DDY-T1-GE3 | D SI4214DY-T1-E3 | ⊛ SI4214DY-T1-GE3 | ⊣ SI4214DY-T1-GE3 |
| ⊛ SI4220-GM | D SI4226DY | ↔ SI4226DY-T1-E3 | ↔ SI4226DY-T1-E3 | ↔ SI4226DY-T1-GE3 |
| ⊣ SI4226DY-T1-GE3 | ⊛ SI4228DY | ↔ SI4228DY-T1-E3 | ↔ SI4228DY-T1-E3 | ↔ SI4228DY-T1-GE3 |
| ⊛ SI4228DY-T1-GE3 | ⊣ SI4232DY | ⊛ SI4276DY-T1-E3 | D SI4276DY-T1-E3 | ↔ SI4282DVP |
| ↔ SI4286DY | ⊛ SI4286DY-T1-GE3 | ⊣ SI4286DY-T1-GE3 | ⊛ SI4288DY | ↔ SI4288DY-T1-GE3 |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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